

60V N-Channel Enhancement Mode MOSFET

Current

45 A

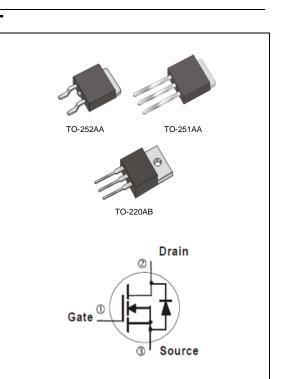
Voltage 60 V

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<12m\Omega$
- $R_{DS(ON)}, V_{GS}@4.5V, I_D@15A<15m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-251AA, TO-252AA , TO-220AB Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.9 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	TO-252AA	UNITS	
Drain-Source Voltage		V _{DS}	60			- V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20				
Continuous Drain Current (Note 4)	T _C =25°C	I _D	45	55	45	A	
	T _C =100°C		29	35	29		
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	180	220	180		
Power Dissipation	T _C =25°C	PD	63	96	63	w	
	T _C =100°C		25	38	25		
Single Pulse Avalanche Energy (Note 6)		E _{AS}	61			mJ	
Operating Junction and Storage Temperature Range		T_J,T_STG	-55~150			°C	
Typical Thermal Resistance (Note	4,5)						
- Junction to Case		$R_{ extsf{ heta}JC}$	2.0	1.3	2.0	°C/W	
- Junction to Ambient		R _{θJA}	110	62.5	110		



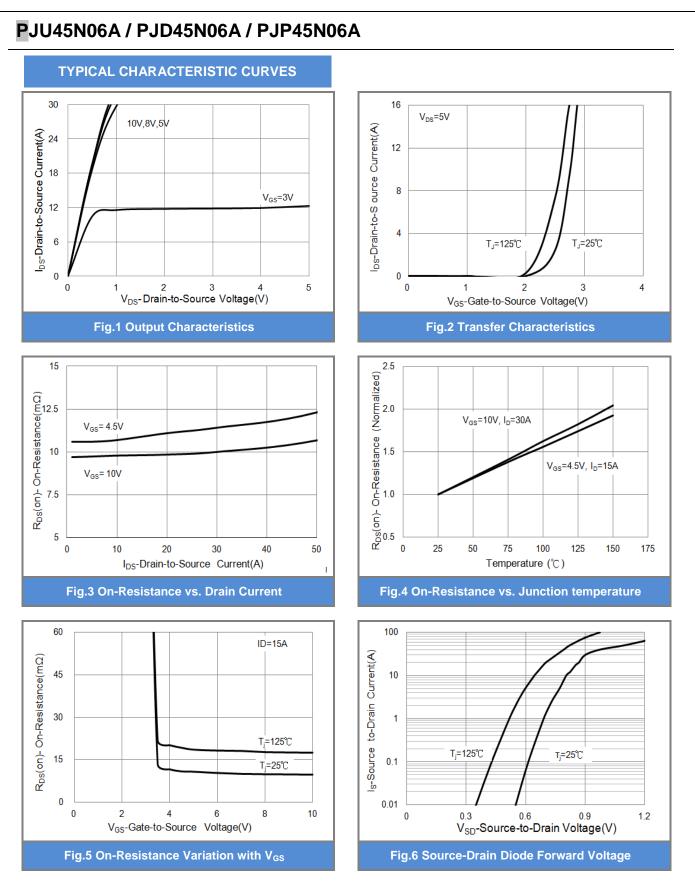
Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1	1.7	2.5	
Drain-Source On-State Resistance		V _{GS} =10V, I _D =20A	-	10.5	12	mΩ
	R _{DS(on)}	V _{GS} =4.5V, I _D =15A	-	12	15	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)		·				
Total Gate Charge	Qg	V_{DS} =30V, I _D =10A, V _{GS} =10V ^(Note 2,3)	-	39	-	nC
Gate-Source Charge	Q _{gs}		-	6.1	-	
Gate-Drain Charge	Q _{gd}		-	6.7	-	
Input Capacitance	Ciss	- V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	2256	-	pF
Output Capacitance	Coss		-	145	-	
Reverse Transfer Capacitance	Crss		-	93	-	
Turn-On Delay Time	td _(on)		-	7.5	-	ns
Turn-On Rise Time	t _r	V _{DD} =15V, I _D =10A, V _{GS} =10V, R _G =6Ω (Note 2.3)	-	36	-	
Turn-Off Delay Time	td _(off)		-	49	-	
Turn-Off Fall Time	t _f		-	12	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S		-	-	45	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.67	1	V

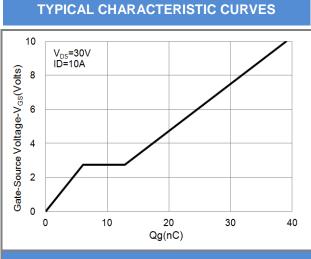
NOTES :

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J=25°C.
- 4. The maximum current rating is package limited.
- 5. $R\Theta_{JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =35A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.











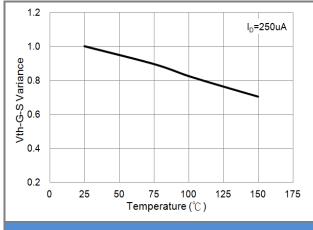
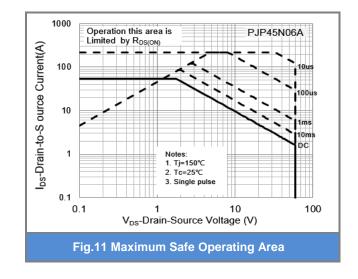
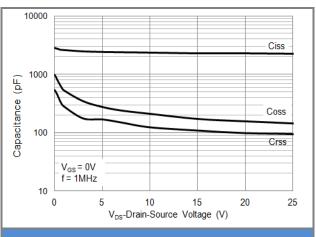


Fig.9 Threshold Voltage Variation with Temperature







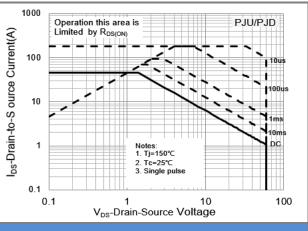
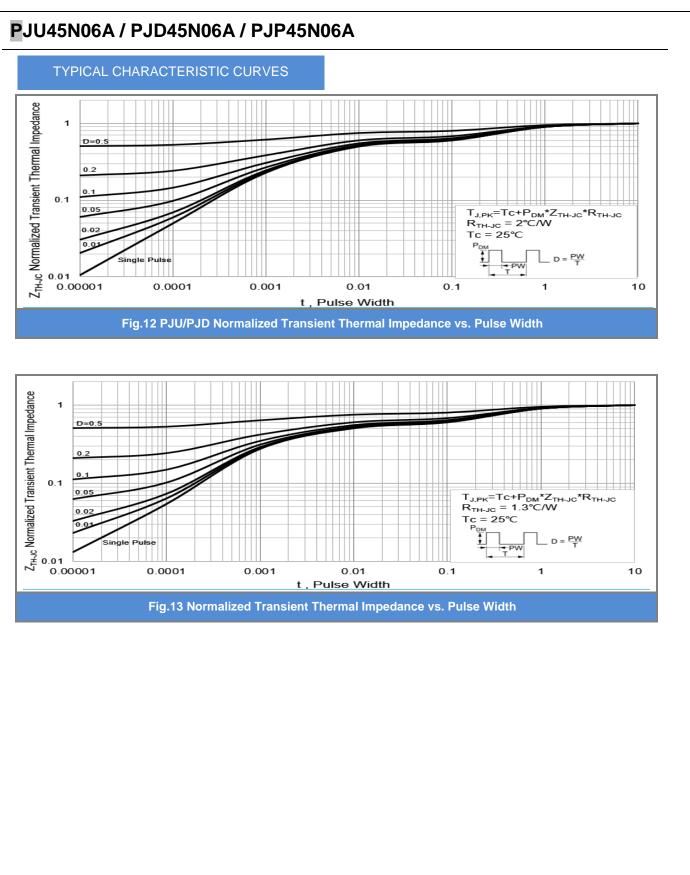


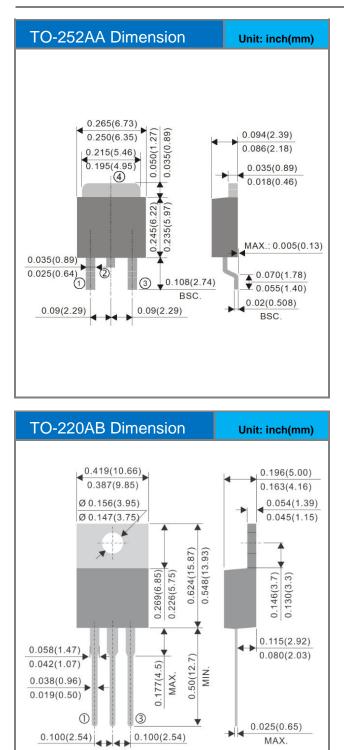
Fig.10 Maximum Safe Operating Area



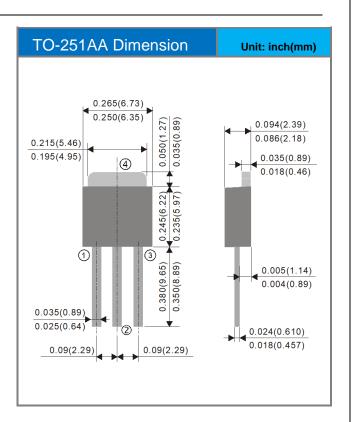




Packaging Information



MAX.



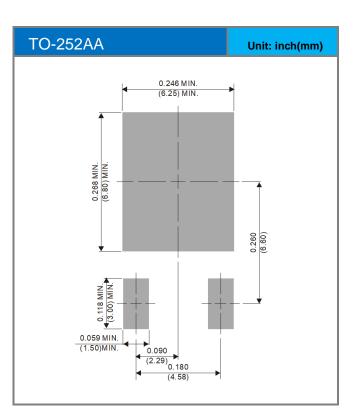
2



Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU45N06A_T0_00001	TO-251AA	80pcs / Tube	U45N06A	Halogen free
PJD45N06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D45N06A	Halogen free
PJP45N06A_T0_00001	TO-220AB	50pcs / Tube	P45N06A	Halogen free

Mounting Pad Layout







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